Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length: 1.480 inches	
Function For Which Designed:	
Bidirectional	
Mounting Facility Quantity:	
1	
Internal Configuration:	
Junction contact	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flats:	
0.561 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Charac	
600.0 repetitive peak off-state voltage	
Current Rating Per Characteristic:	
100.00 amperes peak forward surge	current nanoamperes
Power Rating Per Characteristic:	
16.0 watts small-signal input power,	
Maximum Operating Tempurature	Per Measurement Point:
100.0 degrees celsius ambient air	
Special Features:	
Junction pattern arrangement: pnpn	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
3 tab, solder lug	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	